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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: YAMAGUCHI, et al.  
Serial No.: 09/698,274  
Filed: October 30, 2000  
For: SEMICONDUCTOR DEVICE, METHOD OF MAKING THE  
SAME AND LIQUID CRYSTAL DISPLAY DEVICE  
Group: 2826  
Examiner: F. Abraham

AMENDMENT

Assistant Commissioner of Patents  
Washington, D.C. 20231

August 1, 2002

Sir:

In response to the Office Action mailed May 1, 2002, please amend the  
above-identified application as follows:

IN THE CLAIMS

Please cancel claims 1-3, 11, 16-18 and 34, without prejudice or disclaimer,  
and amend the claims remaining in the application as follows:

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a' 30. (Amended) A thin-film semiconductor integrated circuit device  
comprising a semiconductor thin-film layer provided at the upper part of an insulator,  
a plurality of insulated-gate semiconductor elements formed at said semiconductor  
thin-film layer, each of said semiconductor elements having a gate electrode  
separated from said semiconductor thin-film layer by a gate insulating film at the  
surface of said semiconductor thin-film layer, and a seed crystal metal located